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1. (Currently amended) A light emitting device comprising:

a plurality of pixels arranged in a matrix, each of the plurality of pixels comprising a switching element and a light emitting element, the light emitting element comprising a light emitting layer including an organic compound; and

a plurality of source signal lines for supplying signals to the switching element,

wherein at least one of the plurality of source signal lines comprises a first conductor and a first plated film on upper and side surfaces of the first conductor, and

wherein said first conductor comprises an Ag particle.

2. (Previously presented) A light emitting device according to claim 1, wherein the plated film is formed by an electroplating method.

3. (Previously presented) A light emitting device according to claim 1, wherein the plated film comprises at least one selected from the group consisting of Cu, Al, Au, Ag, and an alloy thereof as a main component.

4. (Previously presented) A light emitting device according to any one of claims 1, wherein the first conductor is made of the same material as a gate electrode of the switching element.

5. (Original) A light emitting device according to claim 1, wherein the switching element comprises at least one thin film transistor.

6. (Original) An electronic appliance comprising the light emitting device according to claim 1, wherein the light emitting device is selected from the group consisting of an electroluminescence display device, a personal computer, and a digital versatile disk.

7. (Currently amended) A light emitting device comprising:

a plurality of pixels arranged in a matrix, each of the plurality of pixels comprising a switching element and a light emitting element, the light emitting element comprising a light emitting layer including an organic compound; and

a plurality of power supply lines for supplying potentials to the light emitting element,

wherein at least one of the plurality of power supply lines comprises a first conductor and a first plated film on upper and side surfaces of the first conductor, and

wherein said first conductor comprises an Ag particle.

8. (Previously presented) A light emitting device according to claim 7, wherein the plated film is formed by an electroplating method.

9. (Previously presented) A light emitting device according to claim 7, wherein the plated film comprises at least one selected from the group consisting of Cu, Al, Au, Ag, and an alloy thereof as a main component.

10. (Previously presented) A light emitting device according to any one of claims 7, wherein the first conductor is made of the same material as a gate electrode of the switching element.

11. (Original) A light emitting device according to claim 7, wherein the switching element comprises at least one thin film transistor.

12. (Original) An electronic appliance comprising the light emitting device according to claim 7, wherein the light emitting device is selected from the group consisting of an electroluminescence display device, a personal computer, and a digital versatile disk.

13. (Currently amended) A light emitting device comprising:

a plurality of pixels arranged in a matrix, each of the plurality of pixels comprising a switching element and a light emitting element, the light emitting element comprising a light emitting layer including an organic compound;

a plurality of source signal lines for supplying signals to the switching element; and

a plurality of power supply lines for supplying potentials to the light emitting element,

wherein at least one of the plurality of source signal lines comprises a first conductor and a first plated film on upper and side surfaces of the first conductor, **[[and]]**

wherein at least one of the plurality of power supply lines comprises a second conductor and a second plated film on upper and side surfaces of the second conductor, and

wherein each of said first conductor and said second conductor comprises an Ag particle.

14. (Previously presented) A light emitting device according to claim 13, wherein at least one of the first plated film and the second plated film is formed by an electroplating method.

15. (Previously presented) A light emitting device according to claim 13, wherein at least one of the first plated film and the second plated film comprises at least one selected from the group consisting of Cu, Al, Au, Ag, and an alloy thereof as a main component.

16. (Original) A light emitting device according to claim 13, wherein the first conductor and the second conductor are simultaneously formed.

17. (Previously presented) A light emitting device according to claim 13, wherein at least one of the first plated film and the second plated film is made of the same material as a gate electrode of the switching element.

18. (Previously presented) A light emitting device according to any one of claims 13, wherein at least one of the first plated film and the second plated film is formed by a printing method.

19. (Original) A light emitting device according to claim 13, wherein the switching element comprises at least one thin film transistor.

20. (Original) An electronic appliance comprising the light emitting device according to claim 13, wherein the light emitting device is selected from the group consisting of an electroluminescence display device, a personal computer, and a digital versatile disk.

CLAIMS 21-86. (CANCELLED)